NSN 5961-01-473-1116

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-473-1116 **Inclosure Material:** Metal and plastic **Overall Length:** 37.07 millimeters **Overall Height:** 4.82 millimeters **Overall Width:** 15.87 millimeters **End Application:** E/ifscm consolidated automated support system cass **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-247 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, average **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Dual diode common cathode **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No